

Supporting Information

High Responsivity, Low Dark Current Ultraviolet Photodetectors based on Two-dimensional Electron Gas Interdigitated Transducers

Peter F. Satterthwaite,^{1,a)} Ananth Saran Yalamarthy,^{2,a)} Noah A. Scandrette,³ A. K. M. Newaz,³ and Debbie G. Senesky^{1,4,b)}

¹*Department of Electrical Engineering, Stanford University, Stanford, California, 94305, USA*

²*Department of Mechanical Engineering, Stanford University, Stanford, California, 94305, USA*

³*Department of Physics and Astronomy, San Francisco State University, San Francisco, California, 94132, USA*

⁴*Department of Aeronautics and Astronautics, Stanford University, Stanford, California, 94305, USA*

^{a)} P. F. Satterthwaite and A. S. Yalamarthy contributed equally to this work

^{b)} Author to whom correspondence should be addressed: dsenesky@stanford.edu

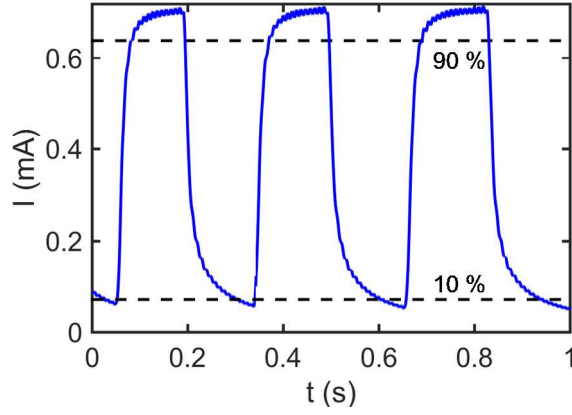


Figure S1. Response time of a 2DEG-IDT photodetector passivated with ~ 20 nm of ALD- Al_2O_3 dielectric to $\sim 0.2 \text{ mW/cm}^2$ 365 nm illumination chopped at ~ 5 Hz. The rise and fall times are ~ 30 ms and ~ 100 ms, respectively, comparable to measurements of devices without alumina.

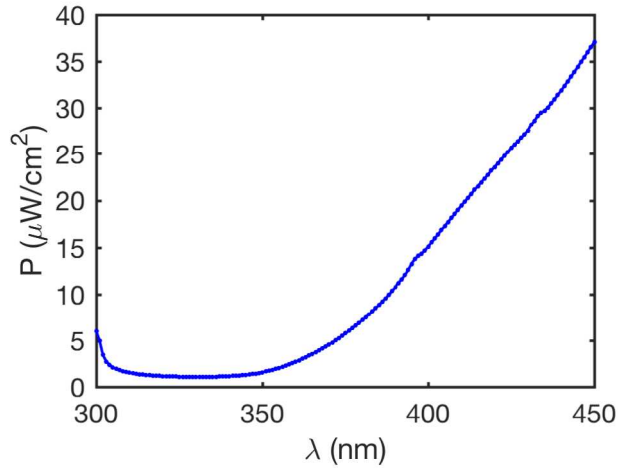


Figure S2. Incident power vs. wavelength calibration curve for Setup II. Incident power was measured using a Hamamatsu S1223 photodetector.